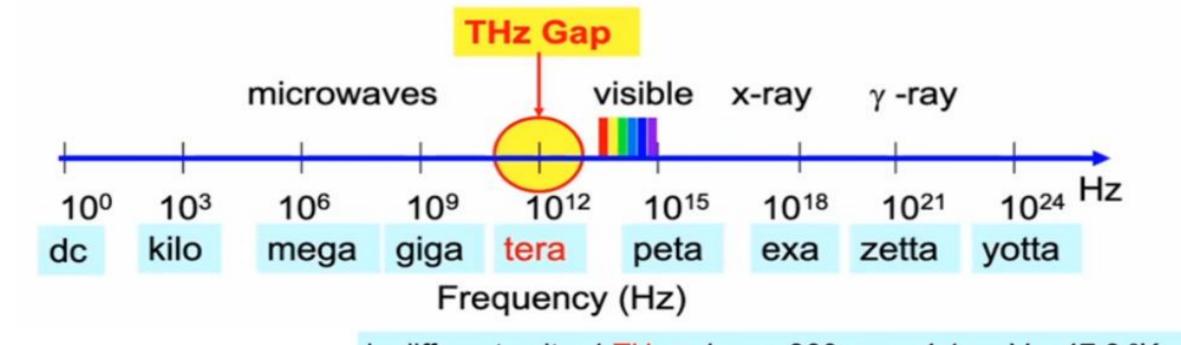
Ultrafast spin-to-charge conversion and spin-dependent transport detected by THz emission

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Introduction

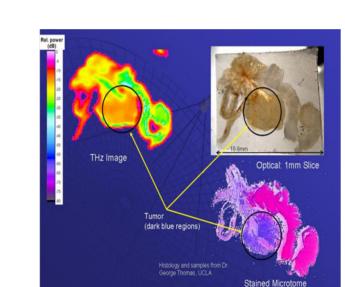


in different units: 1 THz \sim 1 ps \sim 300 μ m \sim 4.1 meV \sim 47.6 °K

Wide THz Applications **Nondestructive**

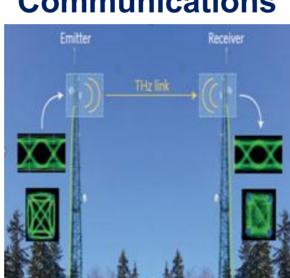
Evaluation

Security Checks

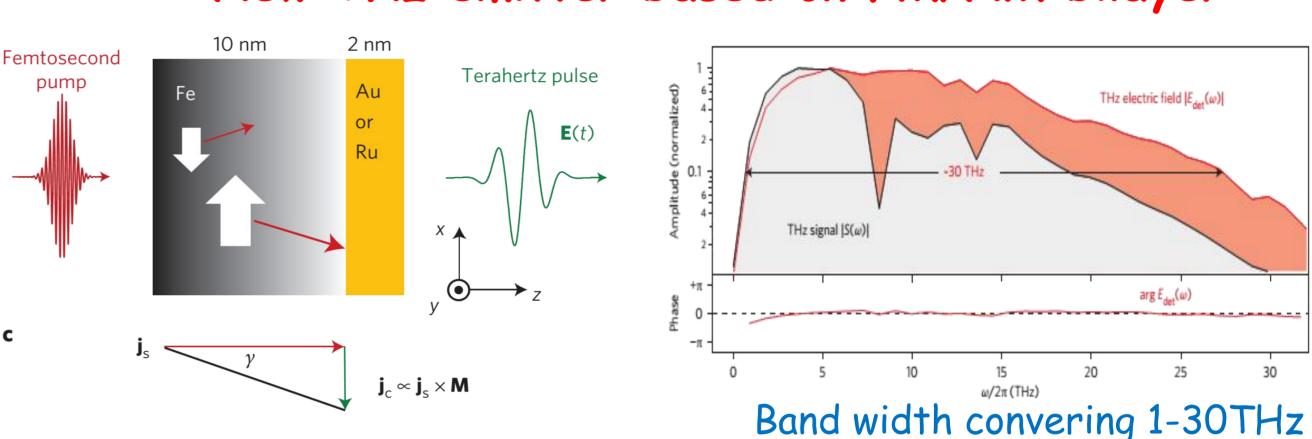


Medical Imaging

Wireless Communications



New THz emitter based on FM/NM bilayer



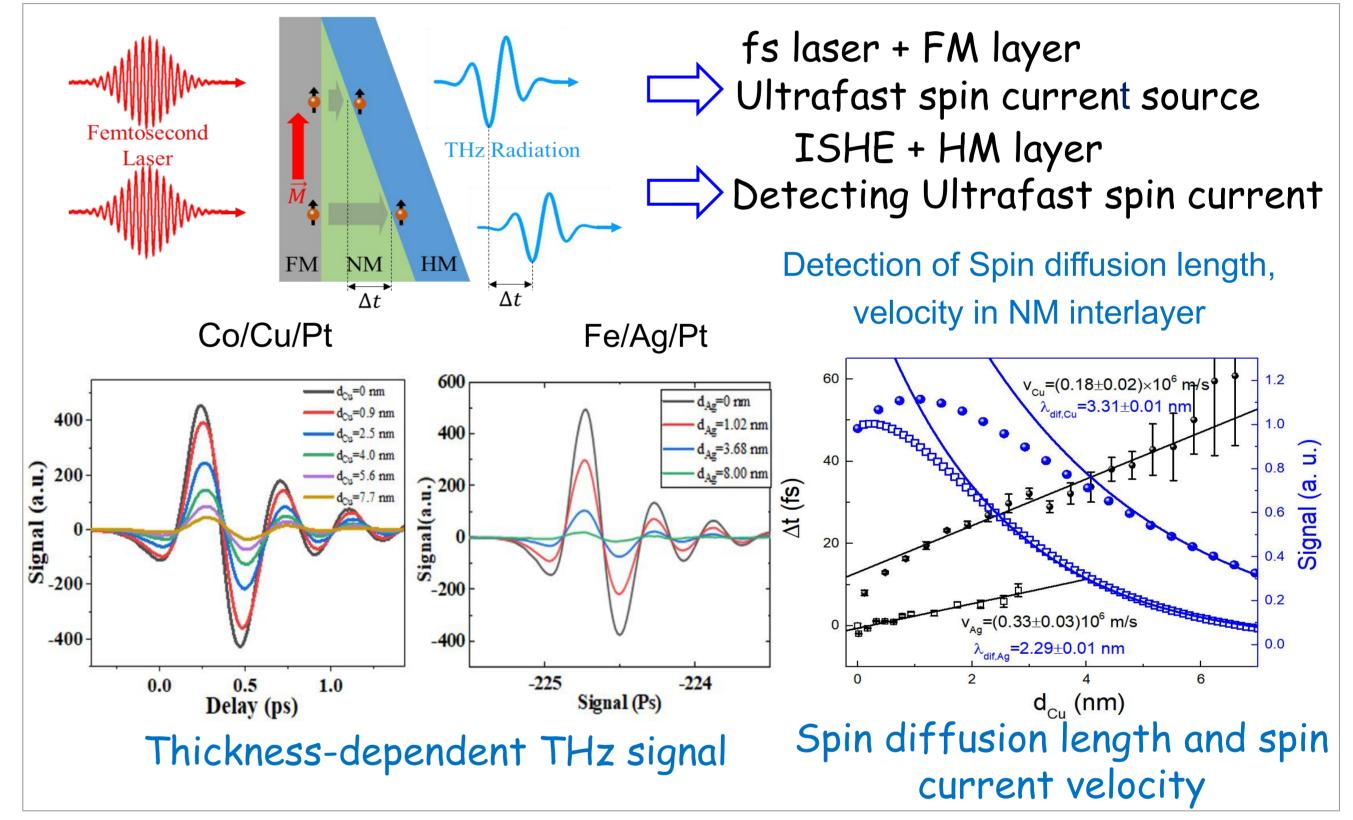
- T. Kampfrath, et al. Nat. Nanotechnol. (2013)
- T. Seifert, et al. Nat. Photonics (2016)
- >New ultrafast spin-to-current conversion Mechanism?
- >THz emission in the confined pattern samples?
- >Ultrafast spin current transport properties?
- >Anistropic terahertz emission in asymmetric crystals?

THz Generation via the interface spin-orbit coupling

Fe/Ag/Bi Fe/Bi/Ag Reversed THz signal Opposite interface THz time domain spectrum Thickness dependent normalized THz signal Fe(2nm)/Ag(2nm)/Bi(d) Fe(2nm)/Bi(d)/Ag(2nm) $d_{\rm Ri}=0$ nm $d_{\rm Bi}=0 \, \rm nm$ 0.3 nmS(t) (a.u.) 0 S(t) (a.u.) 1.6 nm 1.6 nm 2.9 nm 2.9 nm -100 -100 -200 4.0 nm Fe/Ag/Bi 3.6 nm Fe/Bi/Ag 0.5 0.0 0.5 0.0 t (ps) t (ps)

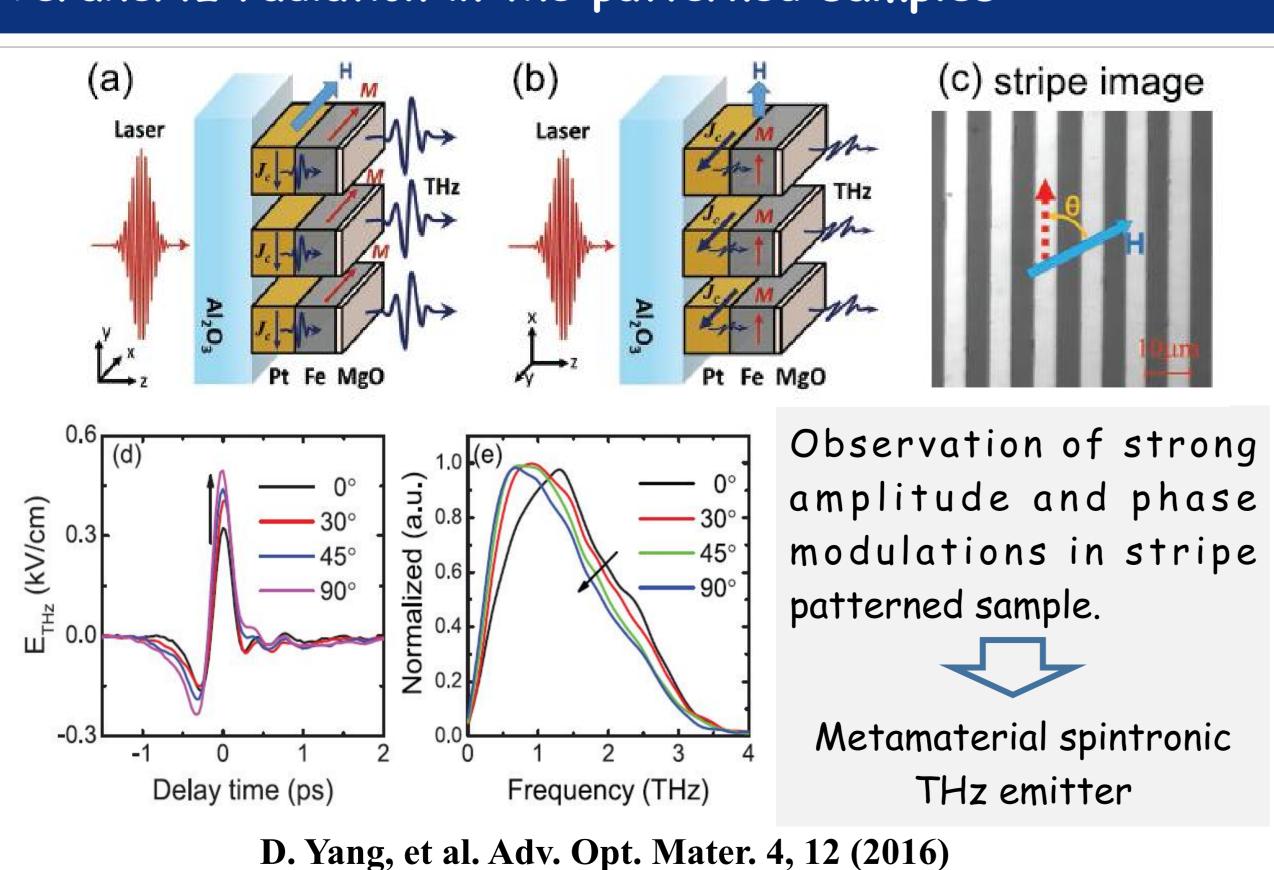
- >Opposite THz signals in Fe/Ag/Bi and Fe/Bi/Ag trilayers with opposite Bi/Ag interface.
- > Constant THz signal independent of the Bi-layer thickness.
- >Prove that inverse Rashba effect can induce the ultrafast spin-charge conversion.
- C. Zhou et al. Phys. Rev. Lett. 121, 086801 (2018)

Spin current transport in Cu and Ag

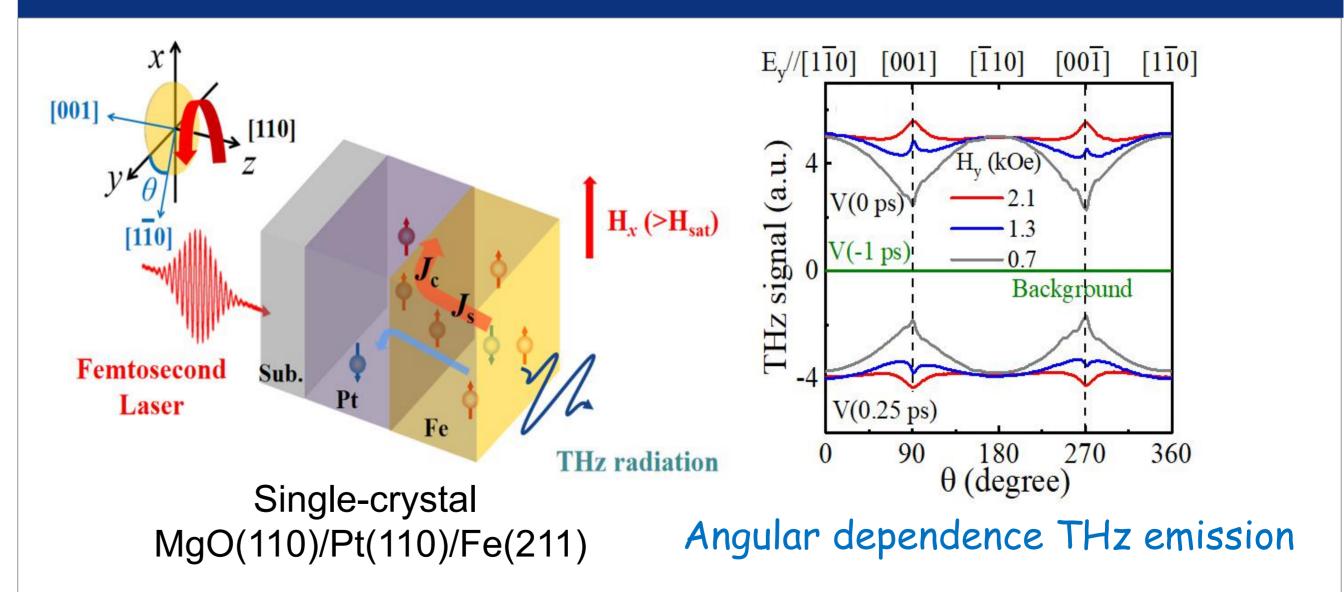


- > Spin relaxation length of ultrafast spin current in non-equilibrium state is two order less than that of the equilibrium electron.
- > The linear relation between the spin current velocity and the inserting layer thickness indicate the ballistic-like transport behavior.

Terahertz radiation in the patterned samples



Anisotropic THz emission in Fe/Pt(110) single crystal



- >Observation of the stronger THz electric field intensity for M along MgO[001] axes than that along MgO[110] axes.
- > The anisotropic THz emission is induced by the lattice distortion induced anisotropic spin Hall conductivity and longitudinal conductance in Pt layer.

C. Liu, et al. Phys. Rev. Applied. 15, 044022 (2021)